

Discrete POWER & Signal **Technologies**

MPS3702



MMBT3702



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5.0	V
Ic	Collector Current - Continuous	800	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units	
		MPS3702	*MMBT3702		
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
$R_{\theta_{JA}}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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PNP General Purpose Amplifier (continued)

Electrical Characteristics TA = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions	Min	Max	Units		
OFF CHARACTERISTICS							
V _{(BR)CEO}	R_{NCEO} Collector-Emitter Breakdown Voltage* $I_{\text{C}} = 10 \text{ mA}, I_{\text{B}} = 0$ 25 V				V		
V _{(BR)CBO}	R_{CBO} Collector-Base Breakdown Voltage $I_{C} = 100 \ \mu A, I_{E} = 0$ 40 V			V			
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \ \mu A, I_C = 0$	5.0		V		

V(BR)CBO	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \ \mu A, I_C = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20 \text{ V}, \text{ I}_{E} = 0$		100	nA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		100	nA

ON CHARACTERISTICS*

h _{FE}	DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 50 \text{ mA}$	60	300	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50$ mA, $I_{\rm B} = 5.0$ mA		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	$I_{\rm C} = 50$ mA, $V_{\rm CE} = 5.0$ V	0.6	1.0	V

SMALL SIGNAL CHARACTERISTICS

Cob	Output Capacitance	$V_{CB} = 10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$		12	pF
fT	Current Gain - Brandwidth Product	$I_{c} = 50 \text{ mA}, V_{ce} = 5.0 \text{ V},$ f = 20 MHz	100		MHz

*Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%



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